

UNISONIC TECHNOLOGIES CO., LTD

### 7N60K

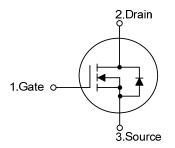
# 7.4A, 600V N-CHANNEL POWER MOSFET

### DESCRIPTION

The UTC 7N60K is a high voltage power MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and have a high rugged avalanche characteristics. This power MOSFET is usually used at high speed switching applications in switching power supplies and adaptors.

#### **FEATURES**

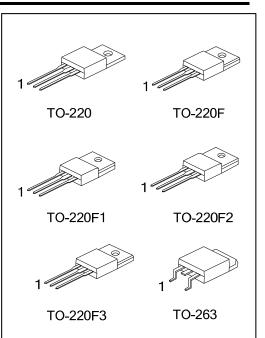
- \*  $R_{DS(ON)}$  < 1.2 $\Omega$  @V<sub>GS</sub> = 10V
- \* Ultra Low Gate Charge (Typical 29 nC)
- \* Low Reverse Transfer Capacitance (C<sub>RSS</sub> = typical 16pF)
- \* Fast Switching Capability
- \* Avalanche Energy Tested
- \* Improved dv/dt Capability, High Ruggedness
- SYMBOL -



#### **ORDERING INFORMATION**

Ordering Number		Deekees	Pin Assignment			Decking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
7N60KL-TA3-T	7N60KG-TA3-T	TO-220	G	D	S	Tube	
7N60K L-TF3-T	7N60KG-TF3-T	TO-220F	G	D	S	Tube	
7N60KL-TF1-T	7N60KG-TF1-T	TO-220F1	G	D	S	Tube	
7N60KL-TF2-T	7N60KG-TF2-T	TO-220F2	G	D	S	Tube	
7N60KL-TF3T-T	7N60KG-TF3T-T	TO-220F3	G	D	S	Tube	
7N60KL-TQ2-T	7N60KG-TQ2-T	TO-263	G	D	S	Tube	
7N60KL-TQ2-R	7N60KG-TQ2-R	TO-263	G	D	S	Tape Reel	
Note: Pin Assignment: G: Gate D: Drain S: Source							

7N60KL- <u>TA3</u> -T (1) Packing Type (2) Package Type (3) Lead Free	<ul> <li>(1) T: Tube, R: Tape Reel</li> <li>(2) TA3: TO-220, TF3: TO-220F, TQ2: TO-263 TF1: TO-220F1, TF2: TO-220F2, TF3: TO-220F3</li> <li>(3) L: Lead Free, G: Halogen Free</li> </ul>	
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**Power MOSFET** 

#### MARKING INFORMATION

PACKAGE	MARKING			
TO-220				
TO-220F	UTC UTC			
TO-220F1				
TO-220F2	Lot Code			
TO-220F3				
TO-263				



	<b>x</b> -		i ,	
PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V <sub>DSS</sub>	600	V
Gate-Source Voltage		V <sub>GSS</sub>	±30	V
Avalanche Current (Note 2)		I <sub>AR</sub>	7.4	А
	Continuous	I <sub>D</sub>	7.4	А
Drain Current	Pulsed (Note 2)	I <sub>DM</sub>	29.6	А
Avalanche Energy	Single Pulsed (Note 3)	E <sub>AS</sub>	220	mJ
	Repetitive (Note 2)	E <sub>AR</sub>	14.2	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	4.5	V/ns
	TO-220/TO-263		142	
Power Dissipation	TO-220F/TO-220F1 TO-220F3	PD	48	w
	TO-220F2		50	
Junction Temperature		TJ	+150	°C
Storage Temperature		T <sub>STG</sub>	-55 ~ +150	°C

#### ■ ABSOLUTE MAXIMUM RATINGS (T<sub>c</sub> = 25°C, unless otherwise specified)

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating : Pulse width limited by maximum junction temperature

3. L = 9mH,  $I_{AS}$  = 7A,  $V_{DD}$  = 90V,  $R_G$  = 25 $\Omega$ , Starting  $T_J$  = 25 $^{\circ}$ C

4.  $I_{SD} \le 7.4A$ , di/dt  $\le 200A/\mu s$ ,  $V_{DD} \le BV_{DSS}$ , Starting  $T_J = 25^{\circ}C$ 

#### THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT	
Junction to Ambient		θ <sub>JA</sub>	62.5	°C/W	
Junction to Case	TO-220/TO-263	θյς	0.88		
	TO-220F/TO-220F1 TO-220F3		2.6	°C/W	
	TO-220F2		2.5		



PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS		OTHIDOL				1017 0 1	UNIT
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250µA	600			V
Drain-Source Leakage Current		I <sub>DSS</sub>	$V_{DS} = 600V, V_{GS} = 0V$			1	μA
	Forward		$V_{GS} = 30V, V_{DS} = 0V$			100	nA
Gate- Source Leakage Current	Reverse	I <sub>GSS</sub>	$V_{GS} = -30V, V_{DS} = 0V$			-100	nA
Breakdown Voltage Temperature Coefficient		$\triangle BV_{DSS} / \triangle T_J$	I <sub>D</sub> =250µA,Referenced to 25°C		0.67		V/°C
ON CHARACTERISTICS			· · ·				
Gate Threshold Voltage		V <sub>GS(TH)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$			4.5	V
Static Drain-Source On-State Res	istance	R <sub>DS(ON)</sub>	$V_{GS} = 10V, I_D = 3.7A$		1.0	1.2	Ω
DYNAMIC CHARACTERISTICS							
Input Capacitance		C <sub>ISS</sub>				1400	pF
Output Capacitance Reverse Transfer Capacitance		C <sub>oss</sub>	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0 MHz			180	pF
		C <sub>RSS</sub>			16	21	pF
SWITCHING CHARACTERISTIC	S						
Turn-On Delay Time		t <sub>D(ON)</sub>				70	ns
Turn-On Rise Time Turn-Off Delay Time Turn-Off Fall Time		t <sub>R</sub>	V <sub>DD</sub> =300V, I <sub>D</sub> =7.4A,		90	170	ns
		t <sub>D(OFF)</sub>	R <sub>G</sub> =25Ω (Note 1, 2)			140	ns
		t <sub>F</sub>			55	130	ns
SWITCHING CHARACTERISTIC	S						-
Total Gate Charge		$Q_{G}$	V <sub>DS</sub> =480V, I <sub>D</sub> =7.4A,		29	38	nC
Gate-Source Charge		$Q_{GS}$	V <sub>DS</sub> =400V, I <sub>D</sub> =7.4A, V <sub>GS</sub> =10V (Note 1, 2)		7		nC
Gate-Drain Charge		$Q_{GD}$			14.5		nC
DRAIN-SOURCE DIODE CHARA	CTERISTIC	S AND MAXI	MUM RATINGS				
Drain-Source Diode Forward Voltage		V <sub>SD</sub>	V <sub>GS</sub> = 0V, I <sub>S</sub> = 7.4 A			1.4	V
Maximum Continuous Drain-Source Diode		la la				7.4	А
Forward Current		ls				1.4	~
Maximum Pulsed Drain-Source Diode		I <sub>SM</sub>				29.6	А
Forward Current		12101				20.0	
Reverse Recovery Time		t <sub>rr</sub>	V <sub>GS</sub> = 0V, I <sub>S</sub> = 7.4 A,		320		ns
Reverse Recovery Charge			dI <sub>F</sub> / dt = 100A/µs (Note 1)		2.4		μC

#### ■ ELECTRICAL CHARACTERISTICS (T<sub>C</sub> =25°C, unless otherwise specified)

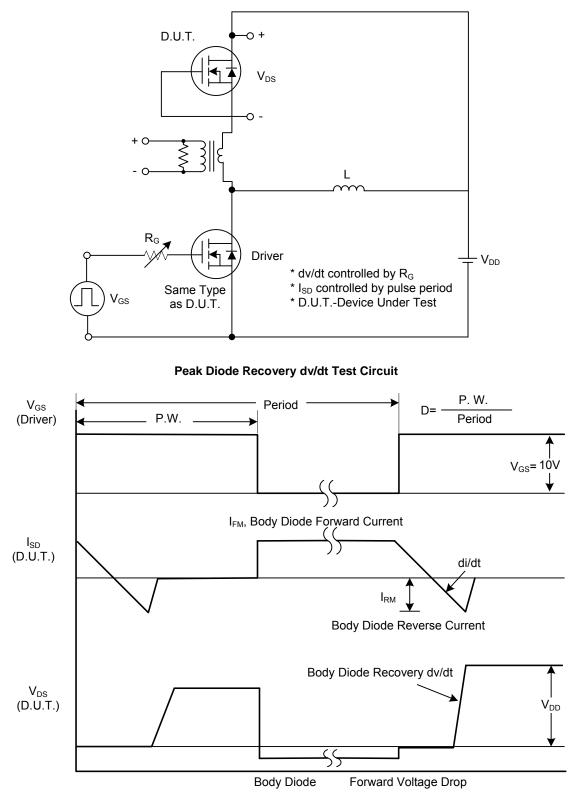
Notes: 1. Pulse Test: Pulse width≤300µs, Duty cycle≤2%

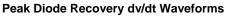
2. Essentially independent of operating temperature



## 7N60K

### TEST CIRCUITS AND WAVEFORMS

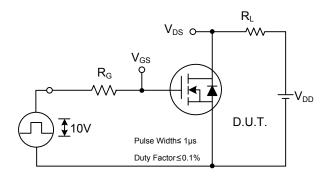




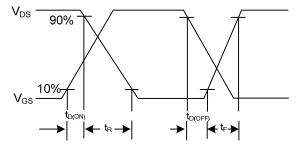


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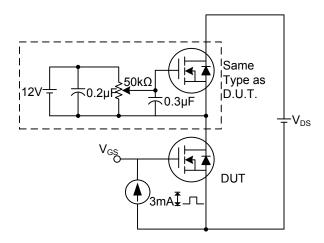
### ■ TEST CIRCUITS AND WAVEFORMS (Cont.)



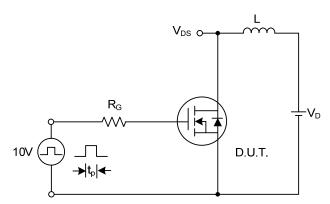
Switching Test Circuit



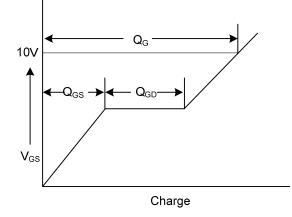
Switching Waveforms



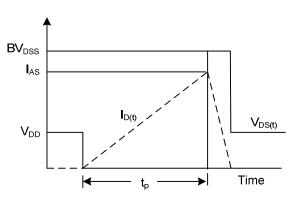
Gate Charge Test Circuit



**Unclamped Inductive Switching Test Circuit** 



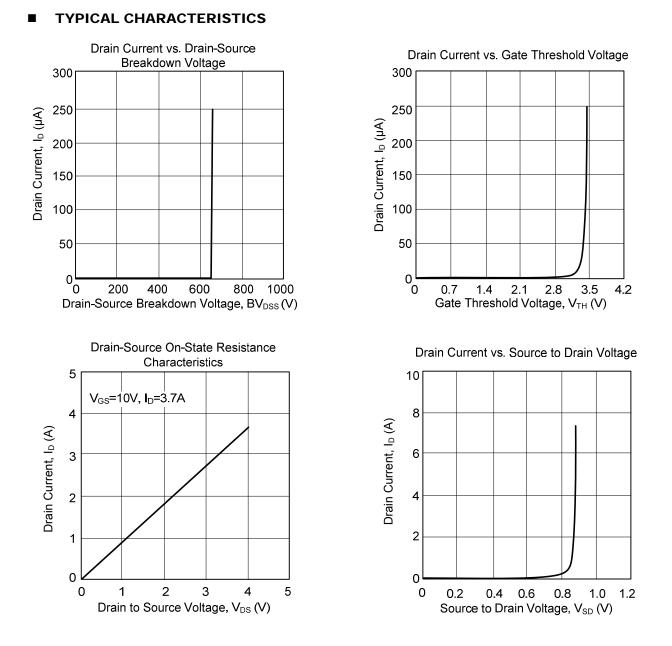




**Unclamped Inductive Switching Waveforms** 



# 7N60K



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